

Triacs logic level

BT136S series D BT136M series D

GENERAL DESCRIPTION

Glass passivated, sensitive gate triacs in a plastic envelope suitable for surface mounting, intended for use in general purpose bidirectional switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

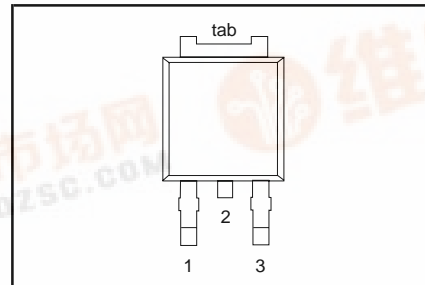
QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX. | MAX. | UNIT |
|---------------------|--|--------------------|--------------------|------|
| V_{DRM} | BT136S (or BT136M)- Repetitive peak off-state voltages | 500D 500 | 600D 600 | V |
| $I_{\text{T(RMS)}}$ | RMS on-state current | 4 | 4 | A |
| I_{TSM} | Non-repetitive peak on-state current | 25 | 25 | A |

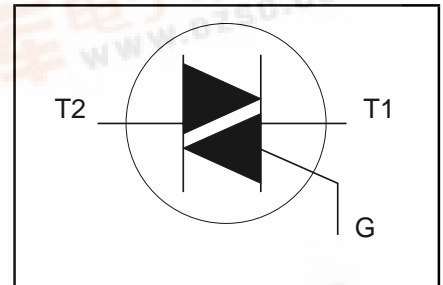
PINNING - SOT428

| PIN NUMBER | Standard S | Alternative M |
|------------|------------|---------------|
| 1 | MT1 | gate |
| 2 | MT2 | MT2 |
| 3 | gate | MT1 |
| tab | MT2 | MT2 |

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | UNIT |
|---------------------|--|---|------|--------------------------|--------------------------|------------------|
| V_{DRM} | Repetitive peak off-state voltages | | - | -500 500 ¹ | -600 600 ¹ | V |
| $I_{\text{T(RMS)}}$ | RMS on-state current | full sine wave; $T_{\text{mb}} \leq 107^\circ\text{C}$ | - | 4 | | A |
| I_{TSM} | Non-repetitive peak on-state current | full sine wave; $T_{\text{j}} = 25^\circ\text{C}$ prior to surge | - | 25 | | A |
| | | $t = 20\text{ ms}$ | - | 27 | | A |
| | | $t = 16.7\text{ ms}$ | - | 3.1 | | A ² s |
| I^2t | I^2t for fusing | $t = 10\text{ ms}$ | - | 3.1 | | A ² s |
| di_{T}/dt | Repetitive rate of rise of on-state current after triggering | $I_{\text{TM}} = 6\text{ A}$; $I_{\text{G}} = 0.2\text{ A}$; $di_{\text{G}}/dt = 0.2\text{ A}/\mu\text{s}$ | - | 50 | | A/ μs |
| | | T2+ G+ | - | 50 | | A/ μs |
| | | T2+ G- | - | 50 | | A/ μs |
| | | T2- G- | - | 50 | | A/ μs |
| | | T2- G+ | - | 10 | | A/ μs |
| I_{GM} | Peak gate current | | - | 2 | | A |
| V_{GM} | Peak gate voltage | | - | 5 | | V |
| P_{GM} | Peak gate power | | - | 5 | | W |
| $P_{\text{G(AV)}}$ | Average gate power | over any 20 ms period | - | 0.5 | | W |
| T_{stg} | Storage temperature | | -40 | 150 | | $^\circ\text{C}$ |
| T_{j} | Operating junction temperature | | - | 125 | | $^\circ\text{C}$ |

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 A/ μs .

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THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|---|---|------|------|------|------|
| $R_{th\ j-mb}$ | Thermal resistance junction to mounting base | full cycle | - | - | 3.0 | K/W |
| $R_{th\ j-a}$ | Thermal resistance junction to ambient | half cycle | - | - | 3.7 | K/W |
| | | pcb (FR4) mounted; footprint as in Fig.14 | - | 75 | - | K/W |

STATIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------|---------------------------|---|------|------|------|------|
| I_{GT} | Gate trigger current | $V_D = 12\ \text{V}$; $I_T = 0.1\ \text{A}$ | - | - | - | - |
| | | T2+ G+ | - | 2.0 | 5 | mA |
| | | T2+ G- | - | 2.5 | 5 | mA |
| | | T2- G- | - | 2.5 | 5 | mA |
| | | T2- G+ | - | 5.0 | 10 | mA |
| I_L | Latching current | $V_D = 12\ \text{V}$; $I_{GT} = 0.1\ \text{A}$ | - | - | - | - |
| | | T2+ G+ | - | 1.6 | 10 | mA |
| | | T2+ G- | - | 4.5 | 15 | mA |
| | | T2- G- | - | 1.2 | 10 | mA |
| | | T2- G+ | - | 2.2 | 15 | mA |
| I_H | Holding current | $V_D = 12\ \text{V}$; $I_{GT} = 0.1\ \text{A}$ | - | 1.2 | 10 | mA |
| V_T | On-state voltage | $I_T = 5\ \text{A}$ | - | 1.4 | 1.70 | V |
| V_{GT} | Gate trigger voltage | $V_D = 12\ \text{V}$; $I_T = 0.1\ \text{A}$ | - | 0.7 | 1.5 | V |
| | | $V_D = 400\ \text{V}$; $I_T = 0.1\ \text{A}$; $T_j = 125\ ^\circ\text{C}$ | 0.25 | 0.4 | - | V |
| I_D | Off-state leakage current | $V_D = V_{DRM(max)}$; $T_j = 125\ ^\circ\text{C}$ | - | 0.1 | 0.5 | mA |

DYNAMIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-----------|---|--|------|------|------|------------------|
| dV_D/dt | Critical rate of rise of off-state voltage | $V_{DM} = 67\% V_{DRM(max)}$; $T_j = 125\ ^\circ\text{C}$; exponential waveform; $R_{GK} = 1\ \text{k}\Omega$ | - | 5 | - | V/ μs |
| t_{gt} | Gate controlled turn-on time | $I_{TM} = 6\ \text{A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1\ \text{A}$; $dl_G/dt = 5\ \text{A}/\mu\text{s}$ | - | 2 | - | μs |

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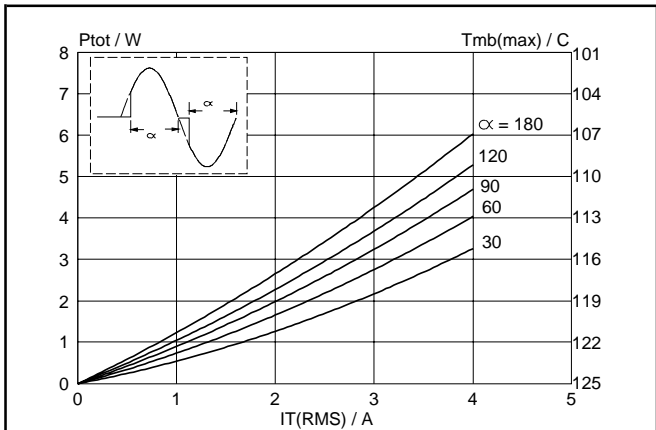


Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle.

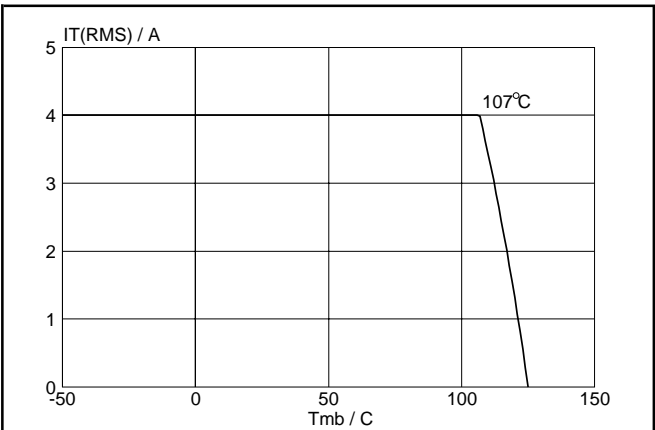


Fig.4. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} .

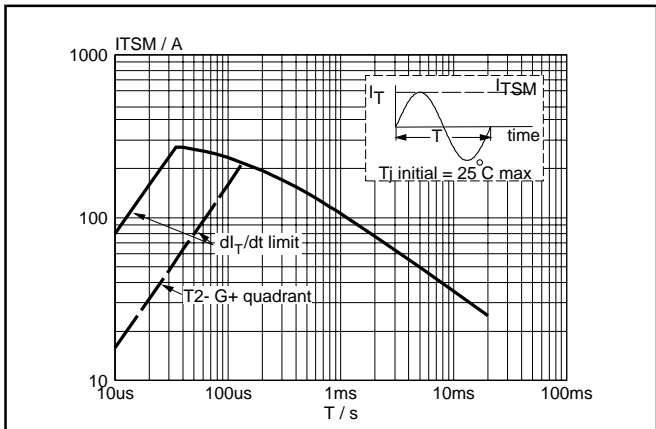


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \leq 20$ ms.

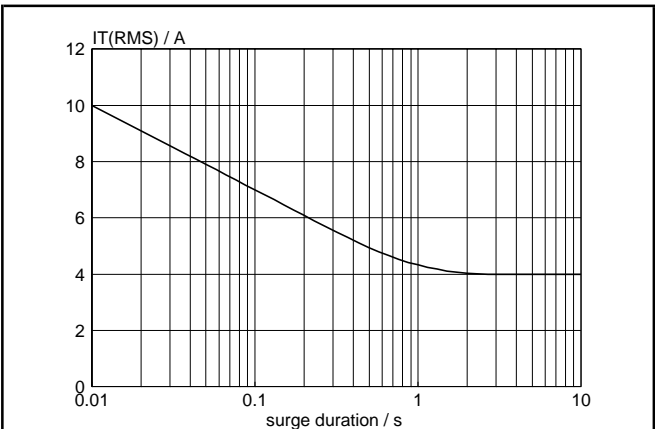


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, $f = 50$ Hz; $T_{mb} \leq 107^\circ\text{C}$.

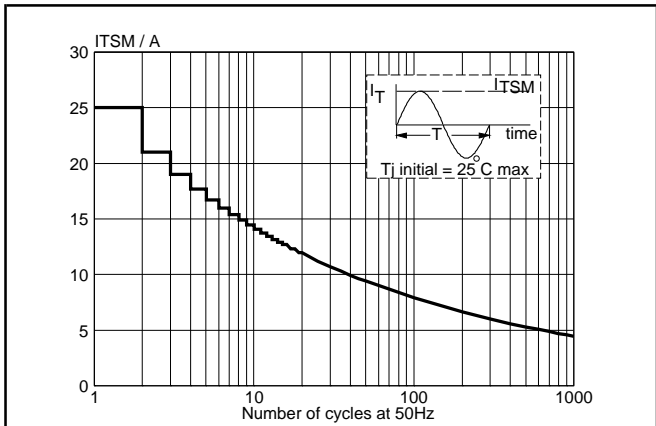


Fig.3. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, $f = 50$ Hz.

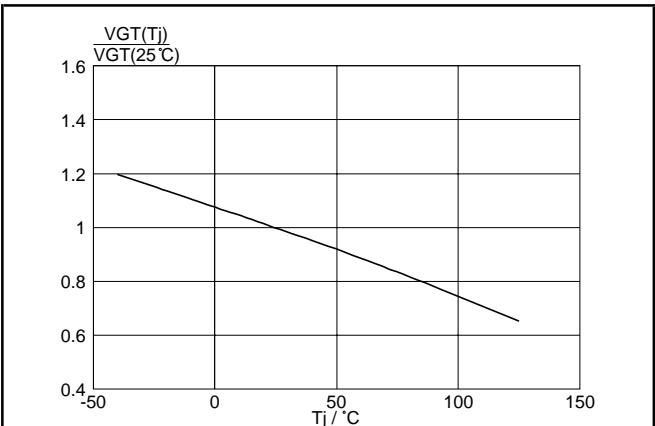
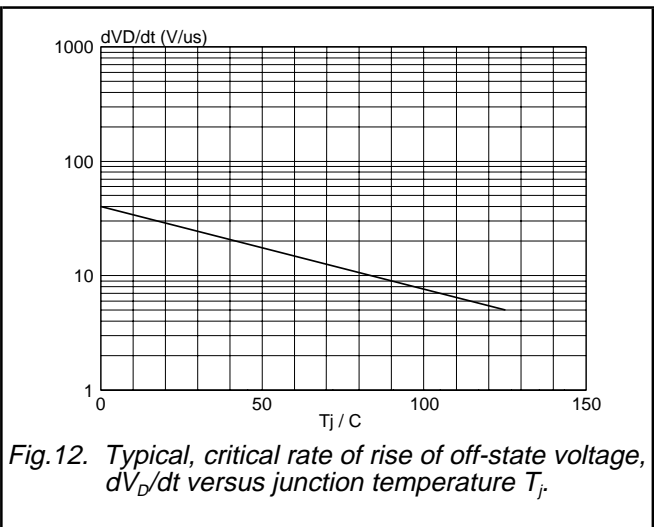
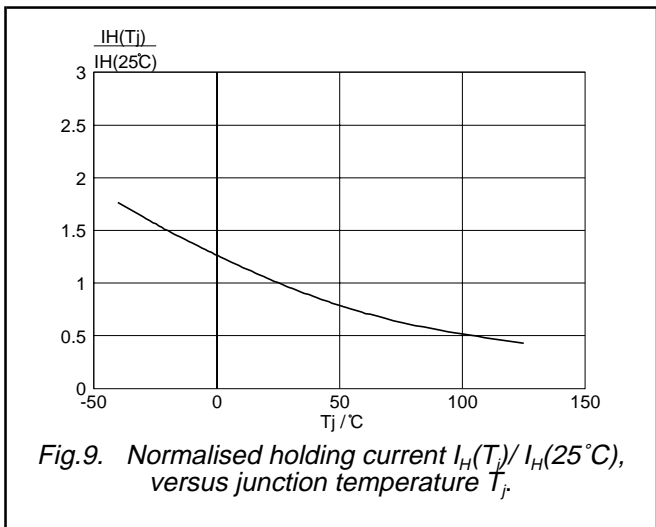
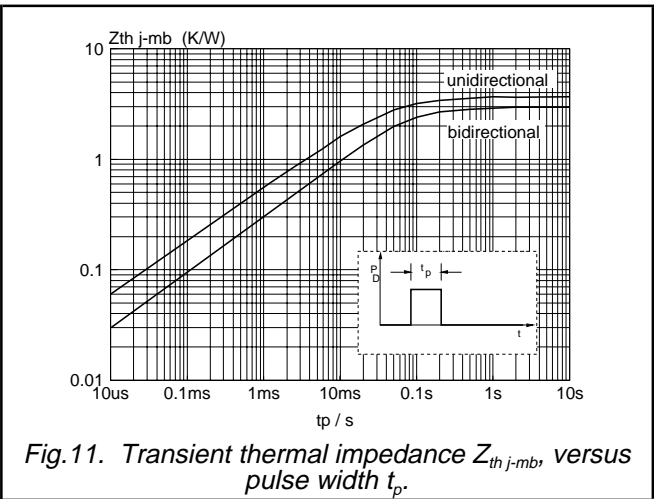
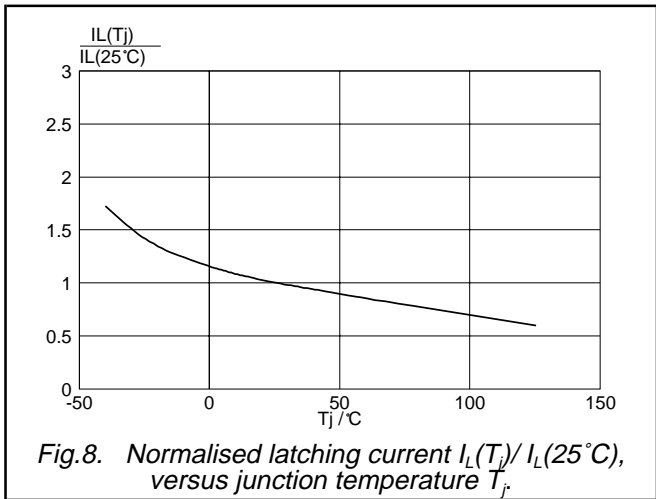
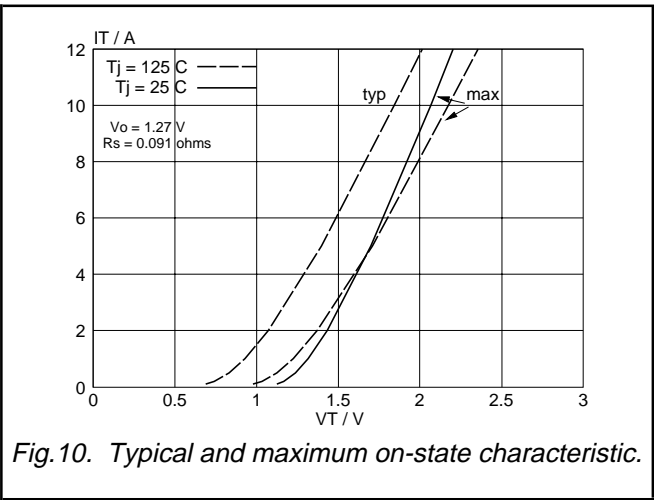
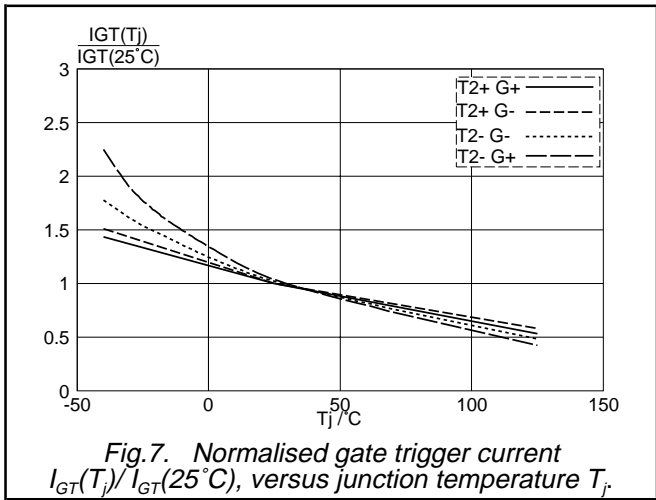


Fig.6. Normalised gate trigger voltage $V_{GT}(T_j) / V_{GT}(25^\circ\text{C})$, versus junction temperature T_j .

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MECHANICAL DATA

Dimensions in mm

Net Mass: 1.1 g

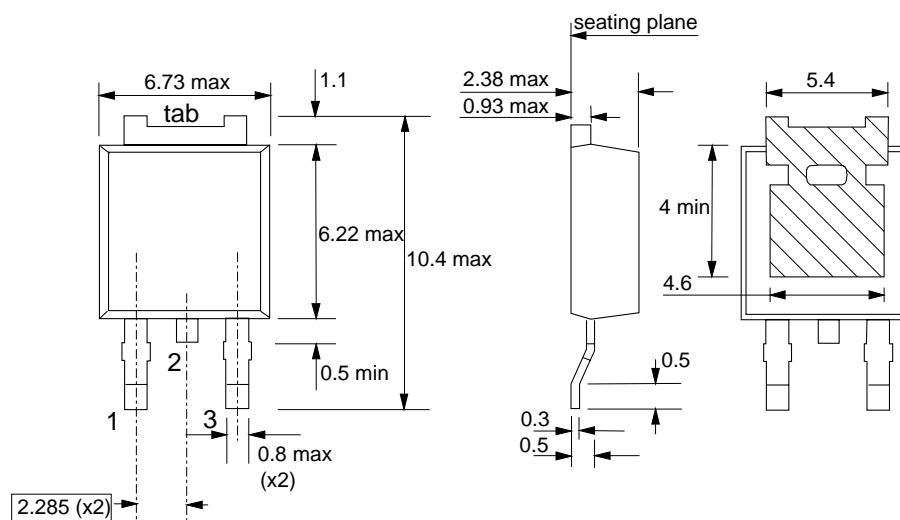


Fig.13. SOT428 : centre pin connected to tab.

MOUNTING INSTRUCTIONS

Dimensions in mm

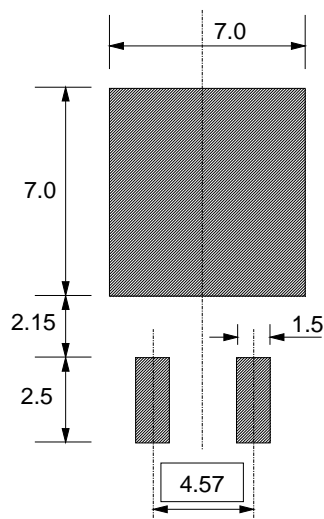


Fig.14. SOT428 : minimum pad sizes for surface mounting.

Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

| Data sheet status | |
|--|---|
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
| Application information | |
| Where application information is given, it is advisory and does not form part of the specification. | |
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